Switch-mode Series NPN Silicon Power Transistor

Designed for high-speed applications.

Features

- Switch-mode Power Supplies
- High Frequency Converters
- Relay Drivers
- Driver
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO(sus)}	90	Vdc
Collector-Base Voltage	V _{CBO}	180	Vdc
Emitter-Base Voltage	V _{EBO}	7.0	Vdc
Collector Current – Continuous	Ι _C	20	Adc
Collector Current – Peak (pw 10 ms)	I _{CM}	30	Adc
Base Current – Continuous	Ι _Β	4.0	Adc
Base Current – Peak	I _{BM}	6.0	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Total Power Dissipation @ $T_C = 60^{\circ}C$	P _D P _D	85 65	W W
Operating and Storage Junction Temperature Range	T _J , T _{stg}	– 65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

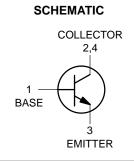
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	1.76	°C/W

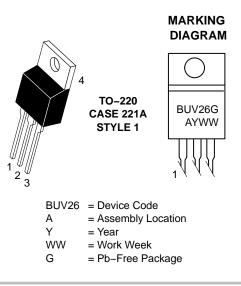


ON Semiconductor®

www.onsemi.com

12 AMPERES NPN SILICON POWER TRANSISTORS 90 VOLTS, 85 WATTS





ORDERING INFORMATION

Device	Package	Shipping
BUV26G	TO-220 (Pb-Free)	50 Units / Rail

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BUV26

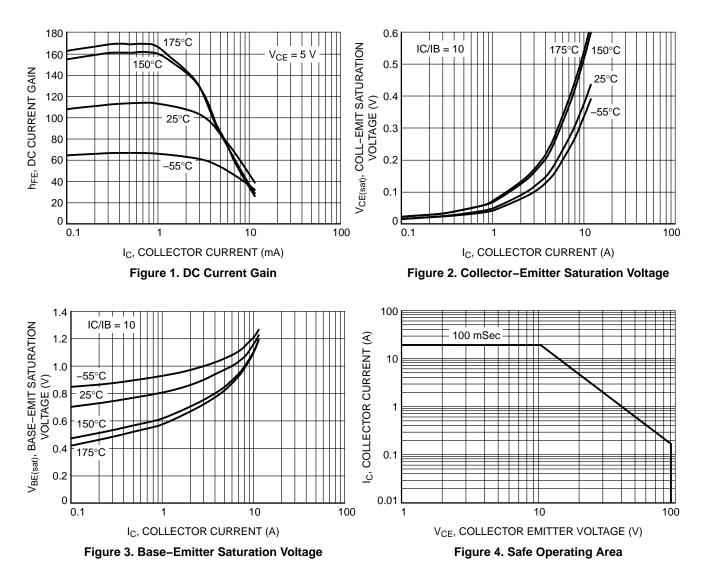
ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERIST	ICS				
Collector–Emitter Sustaining Voltage ($I_C = 200 \text{ mA}, I_B = 0, L = 25 \text{ mH}$)		V _{CEO(sus)}	90	-	Vdc
Collector Cutoff Curre (V_{CE} = 180 V, V_{BE}	ent at Reverse Bias = -1.5 V, T _C = 125°C)	ICEX	_	1.0	mAdc
Emitter Base Reverse (I _E = 50 mA)	e Voltage	V _{EBO}	7.0	30	V
Emitter Cutoff Curren (V _{EB} = 5.0 V)	ıt	I _{EBO}	_	1.0	mAdc
Collector Cutoff Curre (V _{CE} = 180 V, R _{BE}	ent = 50 Ω, T _C = 125°C)	ICER	-	3.0	mAdc
ON CHARACTERISTI	cs				
Collector–Emitter Sat ($I_C = 6.0 \text{ A}, I_B = 0.4$ ($I_C = 12 \text{ A}, I_B = 1.2$	4 A)	V _{CE(sat)}		0.6 1.5	Vdc
Base–Emitter Satura (I _C = 12 A, I _B = 1.2		V _{BE(sat)}	_	2.0	Vdc
SWITCHING CHARAC	CTERISTICS (Resistive Load)				
Turn On Time	I _C = 12 A, I _B = 1.2 A	t _{on}	-	0.6	μs
Storage Time	$V_{CC} = 50 \text{ V}, \text{ V}_{BE} = 6.0 \text{ V}$	t _s	-	1.0	
Fall Time	RB2 = 2.5 Ω	t _f	-	0.15	
SWITCHING CHARAC	TERISTICS (Inductive Load)		·	·	•
Storage Time	$V_{CC} = 50 \text{ V}, I_{C} = 12 \text{ A}$	T _s	-	2.0	μs
Fall Time	$I_{B(end)} = 1.2 \text{ A}, V_{B} = 5.0 \text{ V}$ $L_{B} = 0.5 \text{ pH}, T_{J} = 125^{\circ}\text{C}$	T _f	_	.15	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse width \leq 300 µs; Duty cycle \leq 2%.

BUV26





onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

BUV26 BUV26G